

Subject Code: KEC101T

Roll No:

BTECH

(SEM I) THEORY EXAMINATION 2021-22 EMERGING DOMAIN IN ELECTRONICS ENGINEERING

Time: 3 Hours Total Marks: 100

Note: 1. Attempt all Sections. If require any missing data; then choose suitably.

SECTION A

1. Attempt all questions in brief.

 $2 \times 10 = 20$

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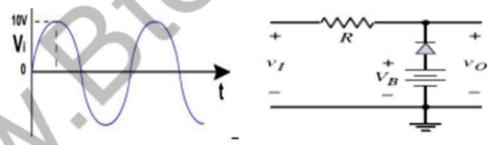
- Determine β , if $I_E = 5$ mA, $I_C = 4.95$ mA.
- Define transconductance of JFET. b.
- What do you mean by CMRR? c.
- d. Differentiate the BJT and JFET.
- $(1010110100.110)_2 = ()_{16}$? e.
- Differentiate between Avalanche and Zener breakdown. f.
- Simplify the Boolean function using Boolean Algebra theorems: g. ABC' + ABC' + ABC' + ABC'
- h. Differentiate between Microprocessor and Microcontroller.
- i. What is Doping? What is the need of Doping?
- j. What is RADAR? Write down two applications of RADAR.

SECTION B

2. Attempt any three of the following:

 $10 \times 3 = 30$

What do mean by clipper? Draw the output waveform of the given circuit.



- Draw the Structure of Depletion type N-MOSFET. Explain its operation with characteristic graph.
 - i) Subtract using 10's complement: $(9754)_{10} - (364)_{10}$
 - Subtract using 1's complement: $(10111)_2 (110011)_2$
- Describe AM modulation and Demodulation technique with adequate diagram.
- Write down the characteristics of ideal OP-AMP. Derive the expression for gain of OP-AMP as non-inverting amplifier.

SECTION C

3. Attempt any *one* part of the following:

 $10 \times 1 = 10$

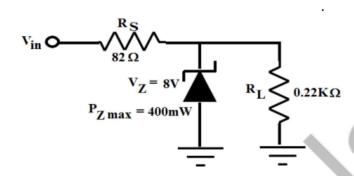
- Define Voltage Multiplier. Draw the circuit and explain the working of voltage (a) Tripler and Quadrupler circuit.
- Draw the V-I charateristics of zener diode. Determine the network of figure (b) given below, determine the range of Vin that will maintain V_L at 8V and not



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exceeded the maximum power rating of the Zener diode.



4. Attempt any *one* part of the following:

 $10 \times 1 = 10$

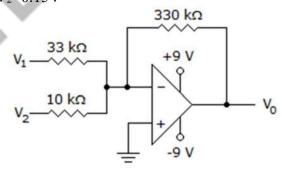
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- (a) Describe the construction and working of a NPN transistor in CE configuration with respect to size and doping. Also, draw the input and output characteristic graph.
- (b) Define α and β with respect to BJT and derive the relationship between them. A transistor having $\alpha=0.975$ and reverse saturation current $I_{CBO}=10\mu A$ is operated in CE mode. If the base current is $250\mu A$. Calculate I_E and I_C .

5. Attempt any *one* part of the following:

 $10 \times 1 = 10$

- (a) (i) Draw and explain the working of Integrator and Differentiator using OP-AMP.
 - (ii) Write Short note on basic elements of communication system.
- (b) (i) Determine the output voltage of an OPAMP for the input voltage of V_1 =150 μ V and V_2 =140 μ V. The amplifier has differential gain A_d =4000 and CMRR is 100.
 - (ii) Determine the output of the following circuit. Given $V_1=V_2=0.15V$



6. Attempt any *one* part of the following:

 $10 \times 1 = 10$

- (a) i) Describe briefly Satellite Communication.
 - ii) Explain Positive and Negative Clamper using suitable circuit diagram and input/output waveform.
- (b) An audio frequency signal $5Sin(2\pi \times 500t)$ is used to amplitude modulate a carrier of $25Sin(2\pi \times 10^5t)$. Calculate:
 - (i) Modulation index
 - (ii) Amplitude of Each side band

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- (iii) Total power
- (iv) Bandwidth
- (v) Transmission efficiency

7. Attempt any *one* part of the following:

 $10 \times 1 = 10$

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- (a) Minimize using K-map and realize using NOR gates only. F (A, B, C, D) = Π M (3, 4, 5, 7, 9, 13, 14, 15). d(0, 2, 8).
- (b) F (A, B, C, D, E) = Σ m (0,1,2,4,5,6,10,13,14,18,21,22,24,26,29,30). Simplify the function with help of K-map and realize the simplified function using basic logic gates.